Single P-channel MOSFET

KFJ4B0622ZL **Datasheet**

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1. GENERAL DESCRIPTION

Single P-channel MOSFET for automotive.

2. FEATURES

- Drain-source On-state Resistance: RDS(on) typ = $56 \text{ m}\Omega$ (VGS = 10 V)
- · CSP (Chip Size Package)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1)
- AEC-Q101 Qualified

3. MARKING SYMBOL: 25

4. PACKAGING

Embossed type (Thermo-compression sealing): 10,000 pcs / reel (standard)

5. ABSOLUTE MAXIMUM RATINGS Ta = 25 °C

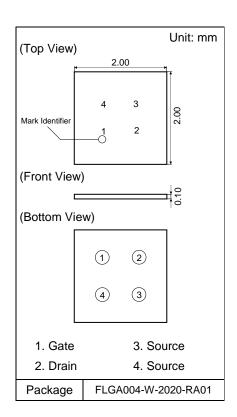
Parameter	Symbol	Rating	Unit		
Drain-source Voltage		VDS	- 60	V	
Gate-source Voltage		VGS	- 20 / + 10	V	
Drain Current	DC *1	ID1	- 2.4		
	DC *2	ID2	- 3.8	^	
	DC *3	ID3	- 4.9	Α	
	Pulsed*4	IDp	- 30.4		
	DC *1	PD1	0.45		
Total Power Dissipation	DC *2	PD2	1.09	W	
	DC *3	PD3	1.79		
Operating Junction and Storage Temperature Range		Tj, Tstg	- 55 to + 150	°C	

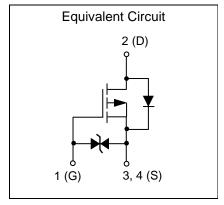
6. THERMAL CHARACTERISTICS Ta = 25 °C

Parameter	Symbol	Rating	Unit
	Rth1 *1	280	
Thermal Resistance (ch-a)	Rth2 *2	115	°C / W
	Rth3 *3	70	

Note *1 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm).
FR4 board partially covered with copper pad (65.2 mm² area, 36 µm thickness).

- *2 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm). FR4 board fully covered with copper pad (616 mm² area, 36 µm thickness).
- *3 Mounted on ceramic board (70 mm x 70 mm x t1.0 mm).
- *4 $t = 10 \mu s$, Duty Cycle $\leq 1 \%$.





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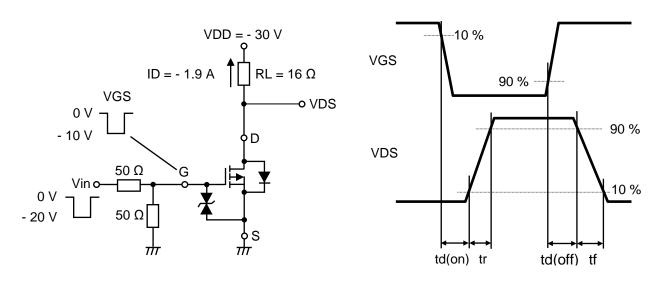
Rev 2.00

7. ELECTRICAL CHARACTERISTICS Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Drain-source Breakdown Voltage	VDSS	ID = - 1 mA, VGS = 0 V	- 60			V	
Zero Gate Voltage Drain Current	IDSS	VDS = - 60 V, VGS = 0 V			- 1	μA	
Cata agurag Lagkaga Current	IGSS	VGS = - 16 V, VDS = 0 V			- 10	μА	
Gate-source Leakage Current		VGS = + 8 V, VDS = 0 V			10		
Gate-source Threshold Voltage	Vth	ID = - 11.2 mA, VDS = - 10 V	- 1	- 2	- 3	V	
Drain-source On-state Resistance	RDS(on)1	ID = - 1.9 A, VGS = - 10 V	39	56	73	mΩ	
	RDS(on)2	ID = - 1.9 A, VGS = - 4.5 V	42	60	100		
Body Diode Forward Voltage	VF(s-d)	IF = - 1.9 A, VGS = 0 V		- 0.77	- 1.2	V	
Input Capacitance *1	Ciss	VDS = - 30 V, VGS = 0 V		3000		pF	
Output Capacitance *1	Coss			110			
Reverse Transfer Capacitance *1	Crss	f = 1 MHz		100			
Turn-on Delay Time *1, *2	td(on)	VDD = - 30 V, VGS = 0 to - 10 V		20			
Rise Time *1, *2	tr	ID = - 1.9 A VDD = - 30 V, VGS = - 10 to 0 V		30		ns	
Turn-off Delay Time *1, *2	td(off)			220			
Fall Time *1, *2	tf	ID = - 1.9 A		90			
Total Gate Charge *1	Qg1	VDD = - 30 V, VGS = - 4.5 V	21				
		ID = - 3.8 A					
	Qg2	VDD = - 30 V, VGS = - 10 V ID = - 3.8 A		43		nC	
Gate-source Charge *1	Qgs			5.5			
Gate-drain Charge *1	Qgd	ID = - 3.0 A		10			

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

- *1 Guaranteed by design, not subject to production testing.
- *2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time.



0.0

0.2

0.4

0.6

Body Diode Forward Voltage, - VF(s-d) (V)

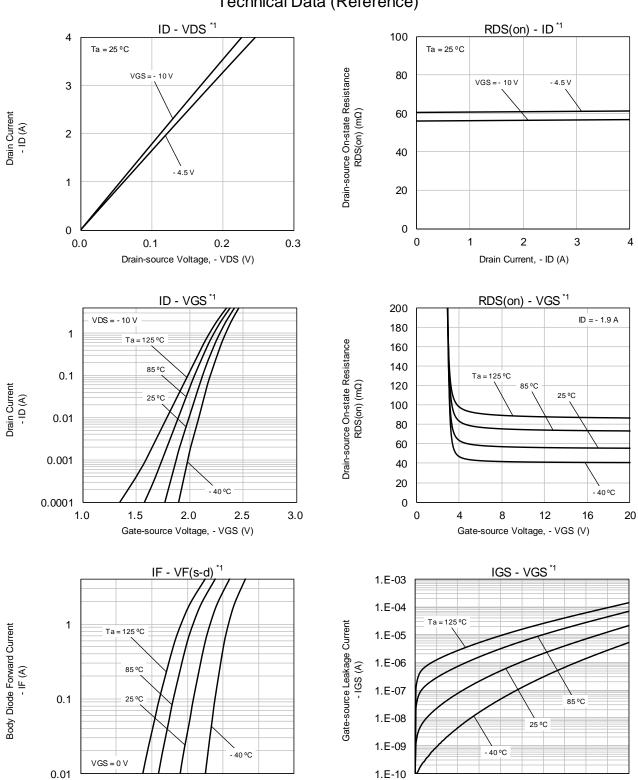
0.8

1.0



8. TECHNICAL DATA (Reference)

Technical Data (Reference)



1.2

2

6 8

Gate-source Voltage, - VGS (V)

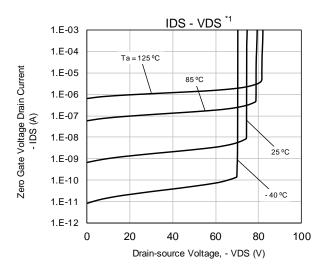
10 12 14 16 18 20

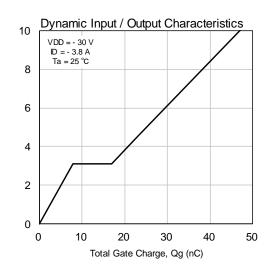
0

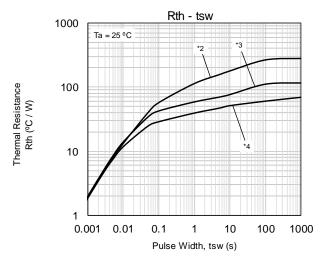
Gate-source Voltage - VGS (V)

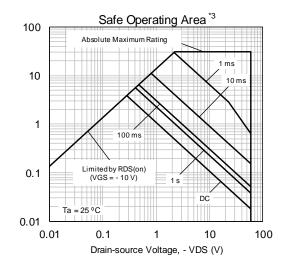
Drain Current - ID (A)

TECHNICAL DATA (Reference)









Note

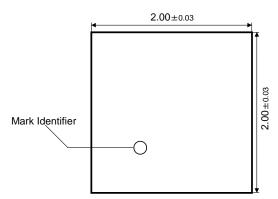
- *1 Pulse measurement.
- * 2 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm). FR4 board partially covered with copper pad (65.2 mm² area, 36 μ m thickness).
- *3 Mounted on FR4 board (25.4 mm x 25.4 mm x t1.0 mm). FR4 board fully covered with copper pad (616 mm² area, 36 µm thickness).
- *4 Mounted on ceramic board (70 mm x 70 mm x t1.0 mm).

Unit: mm

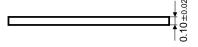


9. OUTLINE

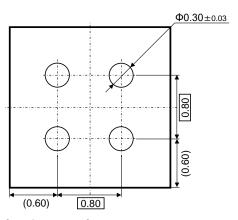
(Top View)



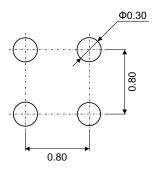
(Front View)



(Bottom View)



10. LAND & STENCIL PATTERN (Reference)



Unit: mm

Important notice:

Solder Mask Defined (SMD) pattern is strongly recommended for pad design.

Please check the information in the Nuvoton WL-CSP Application Notes about mounting process.

ADVANCE INFORMATION



KFJ4B0622ZL

11. REVISION HISTORY

Date	Revision	Description
2021.11.17	1.00	1. Initially issued.
2021.12.21	2.00	1. Added Technical data.



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